## NSN 5961-01-327-3776



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-01-327-3776 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Terminal Length:** 1.500 inches **Overall Height:** 0.350 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole and terminal **Terminal Circle Diameter:** 0.032 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage, dc and 60.0 breakdown voltage, collector-to-emitter, base open and 5.0 emitter to base voltage, dc and 2.5 base to emitter voltage, dc and 4.0 collector to emitter saturation voltage and 3.5 forward voltage, dc **Current Rating Per Characteristic:** Between 5.00 amperes all primaries and 0.10 amperes all primaries and 0.20 milliamperes zero-gate-voltage source current preset and 0.50 milliamperes zero-gate-voltage source current absolute and 2.00 milliamperes zero-gate-voltage source current major **Power Rating Per Characteristic:** 65.0 watts any acceptable absolute **Transfer Ratio:** 1000.0 static forward current transfer ratio, common-emitter **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 pin and 1 case Shelf Life:

**Demilitarization:** Yes - demil/mli

**Unit Of Measure:** 

N/a

## **NSN 5961-01-327-3776** Transistor - Page 2 of 2



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